

DESCRIPTION

The CENTRAL SEMICONDUCTOR C103 Series types are Epoxy Molded Silicon Controlled Rectifiers designed for control systems and sensing circuit applications.

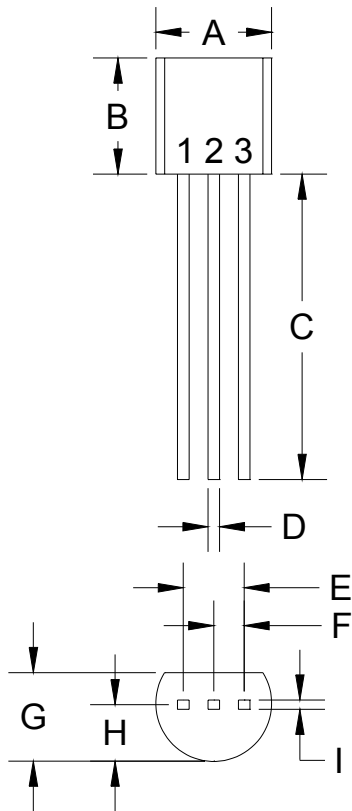
MAXIMUM RATINGS ($T_C=25^\circ\text{C}$ unless otherwise noted)

	<u>SYMBOL</u>	<u>C103Y</u>	<u>C103YY</u>	<u>C103A</u>	<u>C103B</u>	<u>UNITS</u>
Peak Repetitive Off-State Voltage	V_{DRM}, V_{RRM}	30	60	100	200	V
RMS On-State Current ($T_C=60^\circ\text{C}$)	$I_T(\text{RMS})$			0.8		A
Peak One Cycle Surge	I_{TSM}			8.0		A
Peak Forward Gate Current	I_{GM}			0.5		A
Peak Reverse Gate Voltage	V_{GM}			8.0		V
Peak Gate Power Dissipation ($t_p=8.3\text{ms}$)	P_{GM}			1.0		W
Average Gate Power Dissipation	$P_{G(AV)}$			0.01		W
Storage Temperature	T_{stg}		-65 to +150			$^\circ\text{C}$
Junction Temperature	T_J		-65 to +125			$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise noted)

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MIN</u>	<u>TYP</u>	<u>MAX</u>	<u>UNITS</u>
I_{DRM}, I_{RRM}	Rated $V_{DRM}, V_{RRM}, R_{GK}=1\text{K}\Omega$			1.0	μA
I_{DRM}, I_{RRM}	Rated $V_{DRM}, V_{RRM}, T_C=125^\circ\text{C}, R_{GK}=1\text{K}\Omega$			50	μA
I_{GT}	$V_D=6.0\text{V}, R_L=100\Omega, R_{GK}=1\text{K}\Omega$			200	μA
I_{GT}	$V_D=6.0\text{V}, R_L=100\Omega, R_{GK}=1\text{K}\Omega, T_C=-65^\circ\text{C}$			500	μA
I_H	$R_{GK}=1\text{K}\Omega$			5.0	mA
I_H	$R_{GK}=1\text{K}\Omega, T_C=-65^\circ\text{C}$			10	mA
V_{GT}	$V_D=6.0\text{V}, R_L=100\Omega$			0.8	V
V_{GT}	$V_D=6.0\text{V}, R_L=100\Omega, T_C=-65^\circ\text{C}$			1.0	V
V_{GT}	$V_D=6.0\text{V}, R_L=1\text{K}\Omega, T_C=125^\circ\text{C}$	0.1			V
V_{TM}	$I_{TM}=1.0\text{A}$			1.5	V
dv/dt	$V_D=V_{DRM}, T_C=125^\circ\text{C}, R_{GK}=1\text{K}\Omega$		20		V/ μs

TO-92 PACKAGE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

Lead Code: 1) Anode
 2) Gate
 3) Cathode

R1